Electrical reversal of the magnon thermal Hall coefficient in a van der Waals bilayer antiferromagnet

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With spin-layer locking, the manipulation of spin degree of freedom via perpendicular electric field can be realized in a typical antiferromagnetically coupled bilayer. In analogy to the electric control of the anomalous layer Hall effect of electron within such bilayer system, we propose here its magnon counterpart, i.e., the thermal Hall effect controlled by a perpendicular electric field. Unlike electrons, a magnon is charged neutral and its transport in solids can be driven by a thermal gradient. It also exhibits Hall response due to the intrinsic Berry curvature of magnon, analogous to the achievement in electron system. Taking bilayer 2H-VSe₂ with both H-type stacking and interlayer antiferromagnetic coupling as a platform, we perform first-principles calculations towards the magnetic exchange coupling parameters under applied electric field perpendicular to the plane. Based on linear spin wave approximation, we then fit the magnon band structures accordingly and calculate the corresponding Berry curvature. The thermal Hall coefficient dependence on the temperature under thermal gradient can be calculated correspondingly in linear response regime. It is shown that electric field reversal is able to reverse the sign of the coefficient. These findings provide a platform for the realization of all-electric magnon spintronics.

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I. INTRODUCTION

Two-dimensional (2D) van der Waals layered materials provide ideal platforms for the investigation towards the interplay among multiple degrees of freedom of the quasiparticle. Typical studies about electron system with good quantum numbers of charge, spin, valley as well as layer degree of freedom in such systems has recently become of great interest [1-5]. Besides, the interlayer exciton in a bilayer heterojunction, that is, low energy particle-hole excitation within different individual layer, has also attracted intensive attention [6–9]. Importantly, the interlayer tunneling have considerable influence on the interlayer excitation. Also, by applying a perpendicular electric field, which breaks the potential balance between layers, brings about tunable physical properties associated with both intralayer and interlayer quasiparticle excitation. Among bilayer heterostructures, of particular interest is the antiferromagnetically coupled two ferromagnetic monolayer system. It possess spin-layer locking and can achieve the anomalous layer Hall effect [10,11] and the anomalous valley Hall effect [12,13] for an electron controlled by perpendicular electric field. However, the physical motion of charges unavoidably give rise to Joule heating for such electronic system. It is natural to consider a charged neutral magnon excitation for the purpose of obviating dissipation from Joule heating.

As a quasiparticle of spin wave excitation in magnetically ordered system, a magnon can transfer both energy and spin

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over centimeter distance within a magnetic insulator [14,15]. Interestingly, it is widely recognized that in a 2D collinear antiferromagnet exhibiting Néel order along the easy-axis of magnetic anisotropy [16–18], the magnon coherent states can be locked with opposite spin angular momentum characterized by opposite chirality. These can manifest as either left-handed or right-handed precession modes relative to the magnetization axis and be selectively excited and detected [19–22], enabling its coding with binary information similar to the electron spin-1/2 states. For a typical honeycomb lattice, which is staggered with two triangular sublattices possessing opposite perpendicular magnetization [18,23], the two chiral modes can undergo transverse transport under a longitudinal thermal gradient. This transport behavior is driven by their intrinsic Berry curvature, analog to the Hall response observed in electrons. As a consequence of the Dzyaloshinskii-Moriya interaction (DMI) [23-25], this lifts their degeneracy and gains spin Hall current, i.e., magnon spin Nernst effect, which has been observable experimentally [26]. It is noteworthy that this vanishes the heat Hall current owing to symmetry arguments. If the two sets of sublattices are divided into separate layers, as depicted in Fig. 1(a), a straightforward approach would be to apply an electric field perpendicular to the 2D plane. This would break the symmetry, resulting in distinct magnetic exchanges of the two layers. Thus, this will lead to nonvanishing heat transport of the system that can be electrically tunable for such bilayer system.

Along this strategy, in this paper we take bilayer 2H-VSe₂ with H-type stacking as a platform, and set interlayer antiferromagnetic coupling. The degree of freedom of sublattice

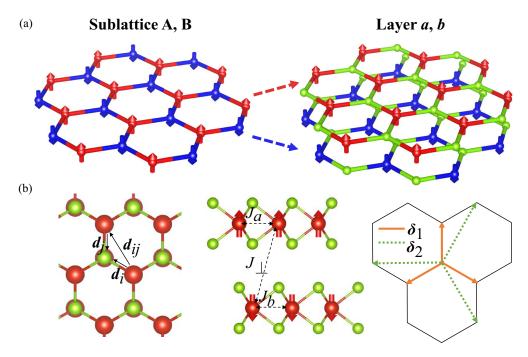


FIG. 1. (a) Scheme of the generalization to the antiferromagnetically coupled bilayer system from an antiferromagnetic monolayer with honeycomb lattice, where the degree of freedom of sublattice A, B in a honeycomb monolayer is now equivalent to the layer degree of freedom a, b in such bilayer. (b) Top view (left) and side view (middle) of H-type stacked bilayer 2H-VSe₂. The magnetization axis is set to be perpendicular to the 2D plane. In the right panel, we show the lattice vector that connects nearest (δ_1) and next-nearest (δ_2) sites, denoted by dashed arrows, in a honeycomb lattice.

A, B in a honeycomb monolayer is now equivalent to the layer degree of freedom a, b in such bilayer. And we perform first-principles calculations towards the magnetic exchange coupling parameters under applied electric field perpendicularly. Then we fit the magnon band structures from these calculated magnetic parameters in the context of linear spin wave approximation utilizing the spin Hamiltonian. It is found that this possesses splitting of the two chiral magnon bands, denoted as α and β , that comes from both internal DMI and the exchange coupling difference induced by the external electric field. It turns out that the magnon energy $\omega_{\alpha}(\pm q) \neq$ $\omega_{\beta}(\mp q)$, causing a population imbalance between the q and -q states. Through calculating the magnon Berry curvature and hence the thermal Hall coefficient in linear response regime, we show that electric field reversal enables the sign change of this coefficient and this will reverse the thermal voltage between the two Hall bars along the sample's boundaries correspondingly.

II. COMPUTATIONAL METHOD AND THEORY

A. First-principles calculations

For the H-type stacked bilayer 2H-VSe₂ with interlayer antiferromagnetic coupling, the optimized lattice constant is 3.335 Å and the interlayer distance between the two Se layers is 3.220 Å. The first-principles calculations are performed with density functional theory (DFT) using the projector augmented wave method implemented in the Vienna *ab initio* Simulation Package (VASP) [27]. The exchange-correlation potential is treated in Perdew-Burke-Ernzerhof form [28] of the generalized gradient approximation

(GGA-PBE) with a kinetic-energy cutoff of 400 eV. Further, we use GGA+U scheme and set the effective Hubbard U repulsion $U_{\rm eff}=1$ eV to correct electron-electron correlation. A well-converged $11\times11\times1$ Monkhorst-Pack k-point mesh is chosen in self-consistent calculations of the unit cell. The convergence criterion for the electronic energy is 10^{-5} eV and the structures are relaxed until the Hellmann-Feynman forces on each atom are less than 1 meV/Å.

The exchange and DMI parameters can be calculated by the four-state method [29,30] based on the spin Hamiltonian. In the supercell static calculations needed for four-states method, we use a $3 \times 3 \times 1$ supercell and $5 \times 5 \times 1$ k-point sampling. For our calculations, the spin-orbit coupling effect was included and the dispersion corrected DFT-D2 method [31] is adopted to describe the van der Waals interactions. The external electric field is introduced with the planar dipole layer method.

B. Spin Hamiltonian of bilayer 2H-VSe₂ system

The individual monolayer of 2H-VSe₂ possess a typical honeycomb lattice of V atomic plane sandwiched between two Se atomic planes [Fig. 1(b)]. As a kind of ferrovalley system for the monolayer, it exhibits spontaneous valley polarization and become an anomalous valley Hall (AVH) insulator [32–34]. For the antiferromagnetically coupled bilayer realized as an antiferrovalley system, the AVH can be electrically controlled via interlayer gate bias [13,35]. These achievements in practice lies on that the 2H-VSe₂ is predicted to be a room-temperature 2D ferromagnet with transition temperature $T_c \sim 590 \, \text{K}$ [36]. And for the bilayer case, it is found

to possess interlayer antiferromagnetism [35,37]. Once the intralayer ferromagnetic order is formed, there exists a large sizable domain in individual layer for the interlayer coupling to remain antiferromagnetic [35]. Moreover, a VSe₂ monolayer system, as a 2D ferromagnet, usually displays an easy plane single-ion magnetic anisotropy demonstrated by many first-principles calculations and also evaluated experimentally [34,38,39]. Yet its magnetization perpendicular to the plane can also be stabilized since the magnetic anisotropy energy can be tuned externally [38,40,41]. Then below for a H-type stacked bilayer antiferromagnet system, which is energetically favorable compared with other types of interlayer stacking, we assume the system undergoes a small perpendicular magnetic anisotropy.

We start by mapping the magnetic energy from a minimal spin Hamiltonian for our bilayer antiferromagnet [42], which is similar to model antiferromagnetic honeycomb lattice [18,23,29,43–45]:

$$H = J_{\perp} \sum_{\langle ij \rangle} \mathbf{S}_{i,a} \cdot \mathbf{S}_{j,b} + \sum_{l} J_{l} \sum_{\langle ij \rangle} \mathbf{S}_{i,l} \cdot \mathbf{S}_{j,l}$$
$$+ \sum_{l} \sum_{\langle ij \rangle} \mathbf{D}_{ij,l} \cdot \mathbf{S}_{i,l} \times \mathbf{S}_{j,l} - K \sum_{i,l} \left(S_{i,l}^{z} \right)^{2}.$$
(1)

Here, $J_{\perp} > 0$ is the interlayer antiferromagnetic exchange between nearest neighbors and $J_l < 0$ is the intralayer ferromagnetic one. For the intralayer coupling, the i i connects the magnetic ions within triangular lattice. The DMI vector survives within the intralayer triangular lattice, denoted as $D_{ij,l}$, and vanishes for the interlayer nearest neighbors because of the presence of the inversion center at the midpoint. Also, different from the antiferromagnetic monolayer case, its planar components $D_{i,l}^{x,y}$ can be nonzero in such a bilayer. However, for such a magnetic ground state of Néel order along z direction, within linear spin wave approximation we will use below, the linear terms of magnon creation or annihilation cancel and no quadratic terms exists [46]. For simplicity we only perform calculations towards the perpendicular components $D_{ij,l}^z$ and specifically it can be expressed as $D_{ij,l}^z = v_{ij}D_l^z$, where v_{ij} $d_i \times d_j \cdot \hat{z}/|d_i \times d_j|$ based on symmetry requirements. The lattice vector d_i , d_j and $d_{ij} = d_i - d_j$ are shown in Fig. 1(c) that connects nearest and next-nearest neighbors, respectively, in the honeycomb lattice of each individual layer. The last term refers to a perpendicular anisotropic term with K > 0in both the a, b layers.

C. Magnon bands

Using the Holstein-Primakoff (HP) transformation [47] for lattice spin S_i with neglecting the magnon-magnon interaction [46,48]:

$$S_{i,a}^{+} \simeq \sqrt{2S}a_{i}, \quad S_{i,a}^{-} \simeq \sqrt{2S}a_{i}^{\dagger}, \quad S_{i,a}^{z} = S - a_{i}^{\dagger}a_{i},$$

 $S_{i,b}^{+} \simeq \sqrt{2S}b_{i}^{\dagger}, \quad S_{i,b}^{-} \simeq \sqrt{2S}b_{i}, \quad S_{i,b}^{z} = b_{i}^{\dagger}b_{i} - S. \quad (2)$

Here $a_i^+(a_i)$ and $b_i^+(b_i)$ corresponds to the magnon bosonic creation (annihilation) operator on site i in layer a and b,

respectively. After taking Fourier transformation

$$a_{\mathbf{q}} = \frac{1}{\sqrt{N}} \sum_{i} a_{i} e^{i\mathbf{q} \cdot \mathbf{R}_{i}}, \quad a_{\mathbf{q}}^{\dagger} = \frac{1}{\sqrt{N}} \sum_{i} a_{i}^{\dagger} e^{-i\mathbf{q} \cdot \mathbf{R}_{i}},$$

$$b_{\mathbf{q}} = \frac{1}{\sqrt{N}} \sum_{i} b_{i} e^{-i\mathbf{q} \cdot \mathbf{R}_{i}}, \quad b_{\mathbf{q}}^{\dagger} = \frac{1}{\sqrt{N}} \sum_{i} b_{i}^{\dagger} e^{i\mathbf{q} \cdot \mathbf{R}_{i}}$$
(3)

this gives (disregarding constant terms)

$$H = S \sum_{q} (M_{q} a_{q}^{\dagger} a_{q} + N_{q} b_{q}^{\dagger} b_{q} + T_{q}^{*} a_{q}^{\dagger} b_{q}^{\dagger} + T_{q} a_{q} b_{q}), \quad (4)$$

where $M_q = 3J_{\perp} + K(2S-1)/S - 2J_a(3-\gamma_q) + 2D_a^z\lambda_q$, $N_q = 3J_{\perp} + K(2S-1)/S - 2J_b(3-\gamma_q) - 2D_b^z\lambda_q$ and $T_q = J_{\perp}t_q$ with $\gamma_q = \sum_{\delta_2} \cos(q \cdot \delta_2)$, $\lambda_q = \sum_{\delta_2} \sin(q \cdot \delta_2)$ and $t_q = \sum_{\delta_1} e^{iq \cdot \delta_1} = |t_q| e^{i\varphi_q}$. Following previous studies about such antiferromagnetic case [23], we use the Bogoliubov quasiparticle representation $\alpha_q = u_q a_q - v_q b_q^{\dagger}$ and $\beta_q = u_q b_q - v_q a_q^{\dagger}$ to diagonalize H_q (see the Appendix).

D. Two magnon chiral modes

It is evident that the spin z component S^z at each site remains conserved in the magnetic ground state, specifically the colinear antiferromagnetic order aligned along the z direction. This conservation is due to the rotational symmetry around the z axis in spin space, denoted as c_z , which is preserved by the spin Hamiltonian. Consequently, the DMI term disappears, satisfying the condition $[S^z, H] = 0$. In consideration of spin wave excitation at low temperature, note that DMI appears, and for each site S^z is not conserved. However, the total spin

$$S^{z} = \sum_{\mathbf{q}} (b_{\mathbf{q}}^{\dagger} b_{\mathbf{q}} - a_{\mathbf{q}}^{\dagger} a_{\mathbf{q}}) = \sum_{\mathbf{q}} (\beta_{\mathbf{q}}^{\dagger} \beta_{\mathbf{q}} - \alpha_{\mathbf{q}}^{\dagger} \alpha_{\mathbf{q}}).$$
 (5)

It can be directly proven that $[S^z, H] = 0$, indicating that within the linear spin wave approximation, the total spin angular momentum S^z along the easy axis remains a good quantum number for magnons, even under the influence of a perpendicular electric field. This electric field solely affects the magnetic parameters without breaking the rotational symmetry around the z axis, denoted as c_z . Moreover, since $\langle \alpha|-S^z|\alpha\rangle=\langle \beta|S^z|\beta\rangle=1$, it gives rise to opposite spin angular momentum $\pm\hbar$ carried by the two modes. Physically, these two magnon modes are locked with opposite chirality that their coherent state can be left-handed or right-handed precession modes with respect to the easy axis.

E. Magnon Berry curvature and thermal Hall coefficient

Since the eigenstates ψ_q are exactly the same for α and β mode, they share the same corresponding Berry curvature of magnon, which can be calculated as [23]

$$\Omega_{\mathbf{q}} = i \langle \nabla_{\mathbf{q}} \psi_{\mathbf{q}} | \times \sigma_{z} | \nabla_{\mathbf{q}} \psi_{\mathbf{q}} \rangle. \tag{6}$$

Here, the σ_z factor comes from the generalized normalization conditions $\langle \psi_q | \sigma_z | \psi_q \rangle = 1$. In the linear response regime [49–51], when a thermal gradient ∇T is uniformly applied along a planar direction of the 2D samples over a sufficiently large area, a transverse thermal current arises [52–54]. Here, the thermal Hall coefficient κ_{xy} is directly proportional to the

TABLE I. Values of the magnetic parameters in the spin Hamiltonian, in units of meV.

	J_{\perp}	J_a	J_b	D_a^z	D_b^z
Our results DFT data in Ref. [55]	0.27 0.25		-14.90 -11.53	0.17	0.17

intrinsic Berry curvature of the magnon:

$$\kappa_{xy} = \frac{k_B^2 T}{\hbar} \sum_{n=\alpha,\beta} \int \frac{d^2 \mathbf{q}}{(2\pi)^2} \Omega_{n\mathbf{q}} c_2(\rho_{n\mathbf{q}}). \tag{7}$$

Here, k_B is Boltzmann constant and $c_2(\rho_{nq})=(1+\rho_{nq})$ $(\ln\frac{1+\rho_{nq}}{\rho_{nq}})^2-(\ln\rho_{nq})^2-2\mathrm{Li}_2(-\rho_{nq}),$ where $\mathrm{Li}_2(z)$ is the polylogarithm function and $\rho_{nq}=1/(e^{\hbar\omega_n(q)/k_BT}-1)$ is the Bose-Einstein distribution function with the chemical potential $\mu=0$ due to that the magnon number does not conserve in consideration of inelastic scatterings [50]. The transverse thermal current of magnon is then expressed as $J_{\epsilon}=\kappa_{xy}\hat{z}\times\nabla T$.

III. RESULTS AND DISCUSSION

In the absence of the perpendicular electric field applied, we extract the total energy and spin magnetic moment $m_s = 1.16 \,\mu_{\rm B}$ on each V ion from first-principles calculations and obtain those parameters as presented in Table I.

The calculated results of the exchange parameters are in agreement with those in previous work [55]. Next, we apply an electric field E_z perpendicular to the plane of the layer, penetrating from layer b to layer a defined as the positive direction. And during the evolution of E_z , the slight difference Δm_s of the spin magnetic moment (about 0.01 μ_B when $E_z = 0.1 \, \mathrm{eV/\mathring{A}}$) between layers and the variation of m_s is ignored at present. The calculated magnetic parameters under E_z are shown in Fig. 2. It is found that within the accuracy we fix, this exhibits a much more significant change of J_l in comparison with that of J_\perp and D_l^z . Specifically, the increase and decrease induced by the electric field of J_a and J_b , respectively, is about 50 times larger than those variations of J_\perp and D_l^z (these two parameters and their variations are almost at the same

order of magnitude). A qualitive explanation for these observations comes from that this induces intralayer electronic polarization, as a dielectric response to a small perpendicular external field E_z in such a bilayer system [35,56]. Since the two magnetic layers are alternatively stacked in an H-type configuration, the application of E_z shifts the charge center of the bilayer, which is originally located at the inversion center when $E_z = 0$. This shift effectively creates an electric dipole. Consequently, this induces both perpendicular and planar charge redistributions within each individual layer. Notably, the planar redistribution significantly affects the overlap of wave functions for the magnetic ions within the triangular lattice, thereby influencing the exchange integral J_l .

A. Calculated magnon spectrum

We show the magnon band structure in Fig. 3 calculated from the magnetic exchange parameters above with setting S=1 and $K=1\,\mu\text{eV}$. When $E_z=0$, as shown in Fig. 3(b), similar to the case of the antiferromagnetic monolayer [23,29], this satisfies $\omega_{\alpha}(\pm q)=\omega_{\beta}(\mp q)$ and here the band splitting merely depends on the internal DMI. It can be shown in the case of in Fig. 3(a) and Fig. 3(c), where $E_z=\pm 0.025\,\text{eV/Å}$, this leads to $\omega_{\alpha}(\pm q)\neq\omega_{\beta}(\mp q)$. The leading contribution that results in this phenomenon comes from the exchange coupling difference J_a-J_b in M_q-N_q term of the magnon energy given by Eq. (A3).

B. Symmetry arguments about the magnon spectrum

To give a symmetry argument, we then expand the spin Hamiltonian in Eq. (1) to the quadratic order in $S_a = \delta S_a + S\hat{z}$ and $S_b = \delta S_b - S\hat{z}$ (setting S = 1 and disregarding constant terms) [23]:

$$H = J_{\perp} \sum_{\langle ab \rangle} \left(\delta \mathbf{S}_{a} \cdot \delta \mathbf{S}_{b} - \delta S_{a}^{z} + \delta S_{b}^{z} \right)$$
$$+ J_{a} \sum_{\langle aa' \rangle} \left(\delta \mathbf{S}_{a} \cdot \delta \mathbf{S}_{a'} - \delta S_{a}^{z} + \delta S_{a'}^{z} \right)$$
$$+ J_{b} \sum_{\langle bb' \rangle} \left(\delta \mathbf{S}_{b} \cdot \delta \mathbf{S}_{b'} - \delta S_{b}^{z} + \delta S_{b'}^{z} \right)$$

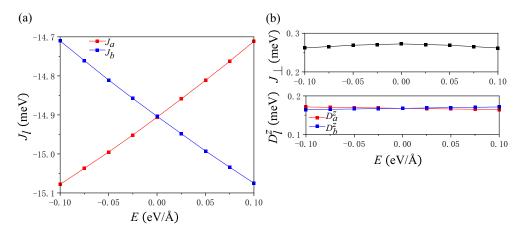


FIG. 2. Calculated (a) planar exchange J_l (b) perpendicular exchange J_{\perp} and DMI parameter D_l^z as the electric field E evolves from -0.1 to 0.1, in units of eV/Å.

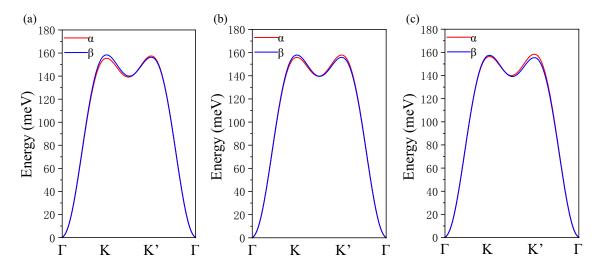


FIG. 3. Magnon band structures along the high-symmetry line Γ -K-K'- Γ in the first Brillouin zone (BZ). They are calculated from the magnetic exchange parameters for (a) $E_z = -0.025 \text{ eV/Å}$, (b) $E_z = 0$, (c) $E_z = 0.025 \text{ eV/Å}$ case.

$$+ D_{a}^{z} \sum_{\langle aa' \rangle} \left(\delta S_{a}^{x} \delta S_{a'}^{y} - \delta S_{a}^{y} \delta S_{a'}^{x} \right)$$

$$- D_{b}^{z} \sum_{\langle bb' \rangle} \left(\delta S_{b}^{x} \delta S_{b'}^{y} - \delta S_{b}^{y} \delta S_{b'}^{x} \right) + K \sum_{a} \left[2 \delta S_{a}^{z} + \left(\delta S_{a}^{z} \right)^{2} \right]$$

$$+ K \sum_{i} \left[-2 \delta S_{b}^{z} + \left(\delta S_{b}^{z} \right)^{2} \right], \tag{8}$$

where, $\langle ab \rangle$ and $\langle aa' \rangle$ denotes the interlayer and intralayer nearest neighborhood, respectively. It is easy to check that in the absence of both external electric field E_z (then $J_a = J_b$ and $D_a^z = D_b^z$) and internal DMI,

$$\mathcal{T}c_r H (\mathcal{T}c_r)^{-1} = H, \tag{9}$$

where the symmetry operations $\mathcal{T}c_x$ of combined timereversal (\mathcal{T}) and a twofold rotation around x axis in the spin space (c_x) act only on the spin deviation δS_a and δS_b while leaving the Néel ground state invariant. Based on HP transformation given in Eq. (2) and Fourier transformation given in Eq. (3), for modes $\alpha_q = u_q a_q - v_q b_q^{\dagger}$ and $\beta_q = u_q b_q - v_q a_q^{\dagger}$, we have

$$\mathcal{T}c_x\alpha_q(\mathcal{T}c_x)^{-1} = -\alpha_{-q}, \quad \mathcal{T}c_x\beta_q(\mathcal{T}c_x)^{-1} = -\beta_{-q}, \quad (10)$$

where we use [57] $\mathcal{T}i\mathcal{T}^{-1}=-i$ and $\mathcal{T}S_{a,b}^{\pm}\mathcal{T}^{-1}=-S_{a,b}^{\mp}$. Here, $S_{a,b}^{\pm}=\delta S_{a,b}^{x}\pm i\delta S_{a,b}^{y}$. Thus, under symmetry operations $\mathcal{T}c_{x}$ onto both left and right side of EOM $\hbar\omega_{\alpha}\alpha_{q}=[\alpha_{q},H]$ and $\hbar\omega_{\beta}\beta_{q}=[\beta_{q},H]$, it requires that $\omega_{\alpha}(q)=\omega_{\alpha}(-q)$ and $\omega_{\beta}(q)=\omega_{\beta}(-q)$. With DMI considered, owing to the DMI part in Eq. (8) is odd under $\mathcal{T}c_{x}$ hence this symmetry is broken so that $\omega(q)\neq\omega(-q)$, as can be seen from the bands splitting shown in Fig. 3(b).

Similar analysis can be used to the combined symmetry operations $\mathcal{P}c_x$, where \mathcal{P} represents the inversion operation, enabling $\mathcal{P}\delta \mathbf{S}_a\mathcal{P}^{-1} = \delta \mathbf{S}_b$. Note that Néel ground state is also invariant under $\mathcal{P}c_x$ operations. We find H is $\mathcal{P}c_x$ invariant if external electric field E switched off. And it can be easy to show that

$$\mathcal{P}c_x\alpha_q(\mathcal{P}c_x)^{-1} = \beta_{-q}, \ \mathcal{P}c_x\beta_q(\mathcal{P}c_x)^{-1} = \alpha_{-q}. \tag{11}$$

Therefore, as expected, $\omega_a(\pm \boldsymbol{q}) = \omega_\beta(\mp \boldsymbol{q})$ for the case of $J_a = J_b$ and $D_a^z = D_b^z$ [Fig. 3(b)]. As E_z switched on, this induces $J_a \neq J_b$ and $D_a^z \neq D_b^z$. Hence, the $\mathcal{P}c_x$ symmetry is not present since it just exchanges the δS_a and δS_b part, not their corresponding magnetic parameters under such symmetry operations. Yet, the $\mathcal{T}c_x$ symmetry can be preserved as long as DMI is not included. In this manner, we argue that $\omega_a(\pm \boldsymbol{q}) \neq \omega_\beta(\mp \boldsymbol{q})$ in the absence of $\mathcal{P}c_x$ symmetry for the case of $E_z \neq 0$, shown in Figs. 3(a) and 3(c). Moreover, if we exchange both the magnetic parameters J_a with J_b and D_a^z with D_b^z under $\mathcal{P}c_x$ operations, H is invariant, which is indicated by the symmetry between the magnon band structures under E_z and $-E_z$.

We also plot the calculated magnon Berry curvature in Fig. 4 for the case of $E_z=0$. Notably, its antisymmetric distribution under ${\bf q} \to -{\bf q}$ relies on an effective time reversal symmetry for magnon. Under such symmetry operations, since $D_a^z=D_b^z$, $\theta_{\bf q}=\theta_{-\bf q}$ and $\varphi_{-\bf q}=-\varphi_{\bf q}$ so that $\Omega_{-\bf q}=-\Omega_{\bf q}$. It also reflects that this symmetry is preserved for $\psi_{\bf q}$ such that $\psi_{-\bf q}=\psi_{\bf q}^*$. When $E_z\neq 0$ hence $D_a^z\neq D_b^z$, because of the DMI term $D_a^z-D_b^z$ in $M_{\bf q}+N_{\bf q}$ introduced into the expression of Berry curvature, that antisymmetry no longer exists. It is indicated that the effective time reversal symmetry is broken so that $\psi_{-\bf q}\neq\psi_{\bf q}^*$.

C. Electrical reversal of the magnon thermal Hall voltage

Given that $\omega_{\alpha}(\pm \boldsymbol{q}) \neq \omega_{\beta}(\mp \boldsymbol{q})$ under perpendicular electric field E_z switched on, it is apparent that driven by a longitude thermal gradient, the thermal Hall transport cannot vanish identically caused by the distribution imbalance $\rho_{q} \neq \rho_{-q}$ of the thermal magnon, distinct from that case of $E_z = 0$. Clearly, earlier symmetry arguments show that when $E_z = 0$, $\Omega_{-q} = -\Omega_{q}$ and $\rho_{\alpha}(\pm q) = \rho_{\beta}(\mp q)$ so that κ_{xy} vanishes due to the zero integral over the Brillouin zone (BZ) for an odd function. As plotted in Fig. 5(a), we reveal that the calculated thermal Hall coefficient κ_{xy} from Eq. (7) can be nonzero if the perpendicular electric field E_z is switched on. Moreover, this possesses the symmetry requirement that κ_{xy} should be an odd function of the external field E_z , suggesting an electrical

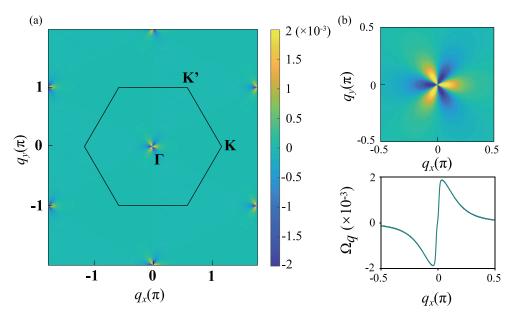


FIG. 4. (a) Calculated Berry curvature Ω_q in the absence of perpendicular electric field. The black hexagon denotes the 2D BZ boundary in wave vector \mathbf{q} space. (b) The distribution of Ω_q around Γ (upper) and along q_x axis (lower).

reversal of the coefficient κ_{xy} . In this sense, we achieve an allelectric control of thermal magnon transport in such a bilayer antiferromagnet. To understand the temperature dependence, one can consider the contribution to the thermal Hall coefficient κ_{xy} around Γ in BZ, which is primarily influenced by the distribution of the magnon Berry curvature. In this region, thermal magnons of long wavelengths predominate. The significant increase observed after approximately $T > 2.2 \,\mathrm{K}$ can be attributed to adequate thermal excitation of magnons with a substantial Berry curvature. It is worth noting that as $q \to 0$, the Berry curvature rapidly diminishes for thermal magnons, as can be seen in Fig. 4(b). Moreover, the sign changes for the specific finite E case at about T = 2.2 K, clearly shown in the inset figure of Fig. 5(a). This is mainly because below 2.2 K, the calculated κ_{xy} is dominated by the difference of Berry curvature between q and -q states, as we discuss for $E \neq 0$ case. Since there is almost no band splitting between α and β modes below $k_BT \approx 0.2 \,\text{meV}$, the tiny Berry curvature difference of the thermal magnon contribute a tiny value of κ_{xy} . Above 2.2 K, the band splitting for thermal magnon modes dominates. And these two dominated contributions towards κ_{xy} are opposite.

The thermal Hall voltage can be electrically reversed, as shown schematically in Fig. 5(b). Indeed, it is the magnon equivalent of the AVH effect observed in electronic system controlled by a perpendicular electric field E_z [13]. In this scenario, the external electric field selects one of the carriers at the band edge, distinguished by its valley chirality, to attain anomalous velocities. Under E_z and $-E_z$, this give rise to opposite transverse transport because of opposite Berry curvatures and hence the opposite valley charge accumulations on sample boundaries. In such a way, the AVH voltage can be electrically reversed. In analogy, the electric field E_z in our magnon case can choose the net transverse transport between the two chiral magnon modes. The opposite Berry curvatures of the q and -q states give rise to contrasting

energy accumulations in the transverse direction under E_z and $-E_z$, respectively. Consequently, this leads to a reversal in the thermal Hall voltage, which can be practically measured. Thus, such an antiferromagnetically coupled bilayer 2H-VSe₂ is also a good candidate to realize such a magnon thermal Hall effect reversed by electric means.

IV. CONCLUSION

In summary, we theoretically investigate the magnon band structure for an antiferromagnetically coupled bilayer system with H-type stacking, which possesses a triangular magnetic lattice in each individual layer, in analogy to a honeycomb monolayer with Néel antiferromagnetic order. By breaking the symmetry between these two sublattices within the two layers through the external perpendicular electric field we assumed, it is found that the magnon energy $\omega(q) \neq$ $\omega(-q)$ mainly because of the exchange coupling difference of the two layers and hence the imbalance population for the thermal magnon between the q and -q states. Subsequently, with nonzero Berry curvature calculated from the magnon eigenstates we show the thermal Hall transport should occur under a longitude thermal gradient for such a bilayer. Taking the 2H-VSe₂ bilayer antiferromagnet as a platform, we perform first-principles calculations towards the magnetic exchange coupling parameters under applied electric field perpendicularly. Then we fit the corresponding magnon band structures within the linear spin wave approximation and calculate the Berry curvature. Through calculating the thermal Hall coefficient, it is shown that that we can reverse the sign of the thermal Hall voltage by the reversal of the external electric field, which is consistent with our symmetry arguments. Our findings open an appealing route toward functional thin film materials design for low energy consumption devices in all-electric magnon spintronics.

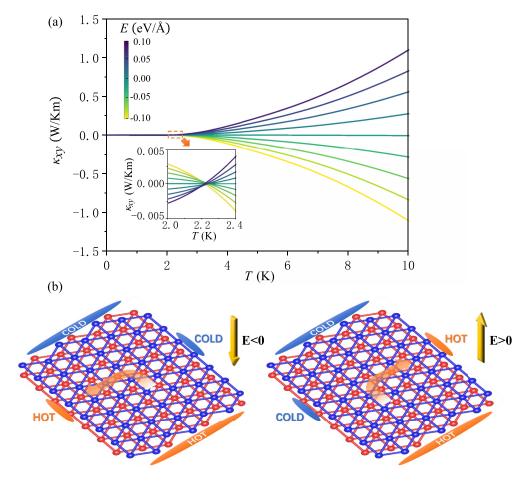


FIG. 5. (a) The thermal Hall coefficient κ_{xy} in units of W/Km versus temperature T. Here we use the distance between two magnetic layers d = 6.35 Å for stacks of two-dimensional layers and divide by the interlayer distance d to get the results (in units of W/Km). The inset figure shows the sign change of κ_{xy} across about 2.2 K. (b) The electric reversal of the thermal Hall voltage. Here, the heater is applied along the longitude direction and we can measure the transverse temperature difference which indicates the sign of the Hall voltage.

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APPENDIX: DIAGONALIZATION OF THE MAGNON HAMILTONIAN

Based on the equation of motion (EOM) $\hbar\omega_{\alpha}\alpha_{q} = [\alpha_{q}, H]$ and $\hbar\omega_{\beta}\beta_{q} = [\beta_{q}, H]$, we will get its matrix representation in the Nambu basis $\binom{a_{q}}{b_{q}^{\dagger}}$ and $\binom{b_{q}}{a_{q}^{\dagger}}$. Through Pauli matrices σ expansion form in particle-hole space, EOM can be written as

$$(\cosh \theta_{q} \sigma_{0} + \sinh \theta_{q} \cos \varphi_{q} \sigma_{x} + \sinh \theta_{q} \sin \varphi_{q} \sigma_{y}) \psi_{q}$$

$$= \varepsilon_{q} \sigma_{z} \psi_{q}, \tag{A1}$$

with $\psi_q = \binom{u_q}{v_q}$ and hyperbolic parametrization:

$$\theta_{q} = \operatorname{arctanh} \frac{2|T_{q}|}{M_{q} + N_{q}},$$

$$\varphi_{q} = \operatorname{arg} T_{q}, \ \varepsilon_{q} = \frac{\frac{2\hbar\omega}{S} \pm (M_{q} - N_{q})}{\sqrt{(M_{q} + N_{q})^{2} - 4|T_{q}|}}.$$
(A2)

Here, + corresponds to the case of α mode and - corresponds to that of β mode, respectively. To solve the eigenproblem for such a two-band system, we note that the EOM given by Eq. (A1) has the form $H\psi_q = \sigma_z \varepsilon_q$. Also, the diagonalization of H gives the identity matrix $\langle \psi_q | H | \psi_q \rangle = 1$. The eigenvalue $\varepsilon_q = \pm 1$ corresponds to the positive and negative branch of the band structure with eigenstates that satisfy $\langle \psi_q | \sigma_z | \psi_q \rangle = \pm 1$, respectively. These two modes correspond to quasiparticle and quasihole excitations based on the bosonic commutation relations $[\alpha_q, \alpha_{q'}^+] = \pm \delta_{qq'}$. Now leaving out the negative one, we have the magnon eigenenergy and eigenstates as

$$\hbar\omega_{\alpha,\beta}(\mathbf{q}) = S\left(\sqrt{\left(\frac{M_{\mathbf{q}} + N_{\mathbf{q}}}{2}\right)^2 - |T_{\mathbf{q}}|^2} \mp \frac{M_{\mathbf{q}} - N_{\mathbf{q}}}{2}\right),$$

$$\psi_{\mathbf{q}} = \begin{pmatrix} \cosh\frac{\theta_{\mathbf{q}}}{2} \\ -\sinh\frac{\theta_{\mathbf{q}}}{2}e^{i\varphi_{\mathbf{q}}} \end{pmatrix}.$$
(A3)

Here ψ_q are the same for α and β mode.

- [1] S. H. Pei, Z. H. Wang, and J. Xia, Interlayer coupling: An additional degree of freedom in two-dimensional materials, ACS Nano 16, 11498 (2022).
- [2] X. D. Xu, W. Yao, D. Xiao, and T. F. Heinz, Spin and pseudospins in layered transition metal dichalcogenides, Nat. Phys. 10, 343 (2014).
- [3] C. Y. Jiang, F. C. Liu, J. Cuadra, Z. M. Huang, K. Li, A. Rasmita, A. Srivastava, Z. Liu, and W. B. Gao, Zeeman splitting via spin-valley-layer coupling in bilayer MoTe₂, Nat. Commun. 8, 802 (2017).
- [4] L. Liu, J.-G. Hua, X. J. Zhang, M.-H. Lu, and Y.-F. Chen, Acoustic multiplexing based on higher-order topological insulators with combined valley and layer degrees of freedom, Phys. Rev. Appl. 19, 044055 (2023).
- [5] J. Park, I. W. Yeu, G. Han, C. Jang, J. Y. Kwak, C. S. Hwang, and J. H. Choi, Optical control of the layer degree of freedom through Wannier-Stark states in polar 3R MoS₂, J. Phys.: Condens. Matter 31, 315502 (2019).
- [6] S. Das, G. Gupta, and K. Majumdar, Layer degree of freedom for excitons in transition metal dichalcogenides, Phys. Rev. B 99, 165411 (2019).
- [7] J. S. Ross, P. Rivera, J. Schaibley, E. Lee-Wong, H. Y. Yu, T. Taniguchi, K. Watanabe, J. Q. Yan, D. Mandrus, D. Cobden, W. Yao, and X. D. Xu, Interlayer exciton optoelectronics in a 2D heterostructure p-n junction, Nano. Lett. 17, 638 (2017).
- [8] S. Y. Gao, L. Yang, and C. D. Spataru, Interlayer coupling and gate-tunable excitons in transition metal dichalcogenide heterostructures, Nano. Lett. 17, 7809 (2017).
- [9] J. Hagel, S. Brem, C. Linderalv, P. Erhart, and E. Malic, Exciton landscape in van der Waals heterostructures, Phys. Rev. Res. 3, 043217 (2021).
- [10] R. Peng, T. Zhang, Z. L. He, Q. Wu, Y. Dai, B. B. Huang, and Y. D. Ma, Intrinsic layer-polarized anomalous Hall effect in bilayer MnBi₂Te₄, Phys. Rev. B **107**, 085411 (2023).
- [11] W. B. Dai, H. L. Li, D. H. Xu, C. Z. Chen, and X. C. Xie, Quantum anomalous layer Hall effect in the topological magnet MnBi₂Te₄, Phys. Rev. B **106**, 245425 (2022).
- [12] L. Feng, X. F. Chen, and J. S. Qi, Nonvolatile electric field control of spin-valley-layer polarized anomalous Hall effect in a two-dimensional multiferroic semiconductor bilayer, Phys. Rev. B 108, 115407 (2023).
- [13] W. Y. Tong and C. G. Duan, Electrical control of the anomalous valley Hall effect in antiferrovalley bilayers, npj Quant. Mater. **2**, 47 (2017).
- [14] H. Katsura, N. Nagaosa, and P. A. Lee, Theory of the thermal Hall effect in quantum magnets, Phys. Rev. Lett. 104, 066403 (2010).
- [15] Y. Onose, T. Ideue, H. Katsura, Y. Shiomi, N. Nagaosa, and Y. Tokura, Observation of the magnon Hall effect, Science 329, 297 (2010).
- [16] A. V. Chumak, V. I. Vasyuchka, A. A. Serga, and B. Hillebrands, Magnon spintronics, Nat. Phys. 11, 453 (2015).
- [17] A. V. Chumak, A. A. Serga, M. B. Jungfleisch, R. Neb, D. A. Bozhko, V. S. Tiberkevich, and B. Hillebrands, Direct detection of magnon spin transport by the inverse spin Hall effect, Appl. Phys. Lett. 100, 082405 (2012).
- [18] V. A. Zyuzin and A. A. Kovalev, Magnon spin Nernst effect in antiferromagnets, Phys. Rev. Lett. 117, 217203 (2016).
- [19] R. Cheng and Q. Niu, Dynamics of antiferromagnets driven by spin current, Phys. Rev. B **89**, 081105 (2014).

- [20] R. Cheng, J. Xiao, Q. Niu, and A. Brataas, Spin pumping and spin-transfer torques in antiferromagnets, Phys. Rev. Lett. 113, 057601 (2014).
- [21] T. Satoh, S. J. Cho, R. Iida, T. Shimura, K. Kuroda, H. Ueda, Y. Ueda, B. A. Ivanov, F. Nori, and M. Fiebig, Spin oscillations in antiferromagnetic NiO triggered by circularly polarized light, Phys. Rev. Lett. 105, 077402 (2010).
- [22] V. Baltz, A. Manchon, M. Tsoi, T. Moriyama, T. Ono, and Y. Tserkovnyak, Antiferromagnetic spintronics, Rev. Mod. Phys. 90, 015005 (2018).
- [23] R. Cheng, S. Okamoto, and D. Xiao, Spin Nernst effect of magnons in collinear antiferromagnets, Phys. Rev. Lett. 117, 217202 (2016).
- [24] H. T. Zhang and R. Cheng, A perspective on magnon spin Nernst effect in antiferromagnets, Appl. Phys. Lett. 120, 090502 (2022).
- [25] H. Kondo and Y. Akagi, Nonlinear magnon spin Nernst effect in antiferromagnets and strain-tunable pure spin current, Phys. Rev. Res. 4, 013186 (2022).
- [26] Y. Shiomi, R. Takashima, and E. Saitoh, Experimental evidence consistent with a magnon Nernst effect in the antiferromagnetic insulator MnPS₃, Phys. Rev. B 96, 134425 (2017).
- [27] G. Kresse and J. Furthmuller, Efficiency of *ab initio* total energy calculations for metals and semiconductors using a plane-wave basis set, Comp. Mater. Sci. **6**, 15 (1996).
- [28] J. P. Perdew, K. Burke, and M. Ernzerhof, Generalized gradient approximation made simple, Phys. Rev. Lett. 77, 3865 (1996).
- [29] N. Bazazzadeh, M. Hamdi, F. Haddadi, A. Khavasi, A. Sadeghi, and S. M. Mohseni, Symmetry enhanced spin-Nernst effect in honeycomb antiferromagnetic transition metal trichalcogenide monolayers, Phys. Rev. B 103, 014425 (2021).
- [30] H. J. Xiang, E. J. Kan, S. H. Wei, M. H. Whangbo, and X. G. Gong, Predicting the spin-lattice order of frustrated systems from first principles, Phys. Rev. B **84**, 224429 (2011).
- [31] S. Grimme, Semiempirical GGA-type density functional constructed with a long-range dispersion correction, J. Comput. Chem. 27, 1787 (2006).
- [32] W. Y. Tong, S. J. Gong, X. G. Wan, and C. G. Duan, Concepts of ferrovalley material and anomalous valley Hall effect, Nat. Commun. 7, 13612 (2016).
- [33] H. R. Fuh, B. H. Yan, S. C. Wu, C. Felser, and C. R. Chang, Metal-insulator transition and the anomalous Hall effect in the layered magnetic materials VS₂ and VSe₂, New J. Phys. 18, 113038 (2016).
- [34] H. R. Fuh, C. R. Chang, Y. K. Wang, R. F. L. Evans, R. W. Chantrell, and H. T. Jeng, Newtype single-layer magnetic semiconductor in transition-metal dichalcogenides VX_2 (X = S, Se and Te), Sci. Rep. 6, 32625 (2016).
- [35] S. J. Gong, C. Gong, Y. Y. Sun, W. Y. Tong, C. G. Duan, J. H. Chu, and X. Zhang, Electrically induced 2D half-metallic antiferromagnets and spin field effect transistors, Proc. Natl. Acad. Sci. USA 115, 8511 (2018).
- [36] H. Pan, Electronic and magnetic properties of vanadium dichalcogenides monolayers tuned by hydrogenation, J. Phys. Chem. C 118, 13248 (2014).
- [37] M. Esters, R. G. Hennig, and D. C. Johnson, Dynamic instabilities in strongly correlated VSe₂ monolayers and bilayers, Phys. Rev. B **96**, 235147 (2017).
- [38] M. Abdollahi and M. B. Tagani, Tuning the magnetic properties of a VSe₂ monolayer via the magnetic proximity effect

- mediated by Zeeman-type spin-orbit interaction, Phys. Rev. B 108, 024427 (2023).
- [39] X. Wang, D. A. Li, Z. J. Li, C. Z. Wu, C. M. Che, G. Chen, and X. D. Cui, Ferromagnetism in 2D vanadium diselenide, ACS Nano 15, 16236 (2021).
- [40] S. N. Feng and W. B. Mi, Strain and interlayer coupling tailored magnetic properties and valley splitting in layered ferrovalley 2H-VSe₂, Appl. Surf. Sci. 458, 191 (2018).
- [41] W. Rudzinski, Effect of single-ion anisotropy on magnons in the VSe₂ bilayer antiferromagnet, J. Magn. Magn. Mater. 546, 168687 (2022).
- [42] W. Rudziński, J. Barnaś, and A. Dyrdał, Spin waves in bilayers of transition metal dichalcogenides, Phys. Rev. B 109, 035412 (2024).
- [43] S. A. Owerre, Noncollinear antiferromagnetic Haldane magnon insulator, J. Appl. Phys. **121**, 223904 (2017).
- [44] N. Sivadas, M. W. Daniels, R. H. Swendsen, S. Okamoto, and D. Xiao, Magnetic ground state of semiconducting transitionmetal trichalcogenide monolayers, Phys. Rev. B 91, 235425 (2015).
- [45] B. L. Chittari, Y. Park, D. Lee, M. Han, A. H. MacDonald, E. Hwang, and J. Jung, Electronic and magnetic properties of single-layer MPX₃ metal phosphorous trichalcogenides, Phys. Rev. B 94, 184428 (2016).
- [46] S. Park and B. J. Yang, Thermal Hall effect from a two-dimensional Schwinger boson gas with Rashba spinorbit interaction: Application to ferromagnets with in-plane Dzyaloshinskii-Moriya interaction, Phys. Rev. B 102, 214421 (2020).
- [47] T. Holstein and H. Primakoff, Field dependence of the intrinsic domain magnetization of a ferromagnet, Phys. Rev. 58, 1098 (1940).

- [48] Y. Q. Liu, L. J. Zhai, S. S. Yan, D. Wang, and X. G. Wan, Magnon-magnon interaction in monolayer MnBi₂Te₄, Phys. Rev. B 108, 174425 (2023).
- [49] R. Matsumoto and S. Murakami, Theoretical prediction of a rotating magnon wave packet in ferromagnets, Phys. Rev. Lett. 106, 197202 (2011).
- [50] R. Matsumoto and S. Murakami, Rotational motion of magnons and the thermal Hall effect, Phys. Rev. B 84, 184406 (2011).
- [51] D. Xiao, Y. G. Yao, Z. Fang, and Q. Niu, Berry-phase effect in anomalous thermoelectric transport, Phys. Rev. Lett. 97, 026603 (2006).
- [52] K.-S. Kim, K. H. Lee, S. B. Chung, and J.-G. Park, Magnon topology and thermal Hall effect in trimerized triangular lattice antiferromagnet, Phys. Rev. B 100, 064412 (2019).
- [53] Q. H. Chen, F. J. Huang, and Y. P. Fu, Magnon valley thermal Hall effect in triangular-lattice antiferromagnets, Phys. Rev. B 105, 224401 (2022).
- [54] P. Laurell and G. A. Fiete, Magnon thermal Hall effect in kagome antiferromagnets with Dzyaloshinskii-Moriya interactions, Phys. Rev. B 98, 094419 (2018).
- [55] A. L. Li, W. Z. Zhou, J. L. Pan, Q. L. Xia, M. Q. Long, and F. P. Ouyang, Coupling stacking orders with interlayer magnetism in bilayer H-VSe₂, Chin. Phys. Lett. 37, 107101 (2020).
- [56] Y. H. Shen, W. Y. Tong, H. Hu, J. D. Zheng, and C. G. Duan, Exotic dielectric behaviors induced by pseudo-spin texture in magnetic twisted bilayer, Chin. Phys. Lett. 38, 037501 (2021).
- [57] A. Corticelli, R. Moessner, and P. A. McClarty, Spin-space groups and magnon band topology, Phys. Rev. B 105, 064430 (2022).